Integrated Device Technology, Inc.

FAST CMOS OCTAL D REGISTERS (3-STATE)

IDT54/74FCT374/A/C
IDT54/74FCT534/A/C
IDT54/74FCT574/A/C

FEATURES:

- IDT54/74FCT374/534/574 equivalent to FAST™ speed and drive
- **IDT54/74FCT374A/534A/574A up to 30% faster than FAST**
- **IDT54/74FCT374C/534C/574C up to 50% faster than FAST**
- I_{OL} = 48mA (commercial) and 32mA (military)
- CMOS power levels (1mW typ. static)
- Edge triggered master/slave, D-type flip-flops
- Buffered common clock and buffered common three-state control
- Product available in Radiation Tolerant and Radiation Enhanced versions
- Military product compliant to MIL-STD-883, Class B
- Meets or exceeds JEDEC Standard 18 specifications

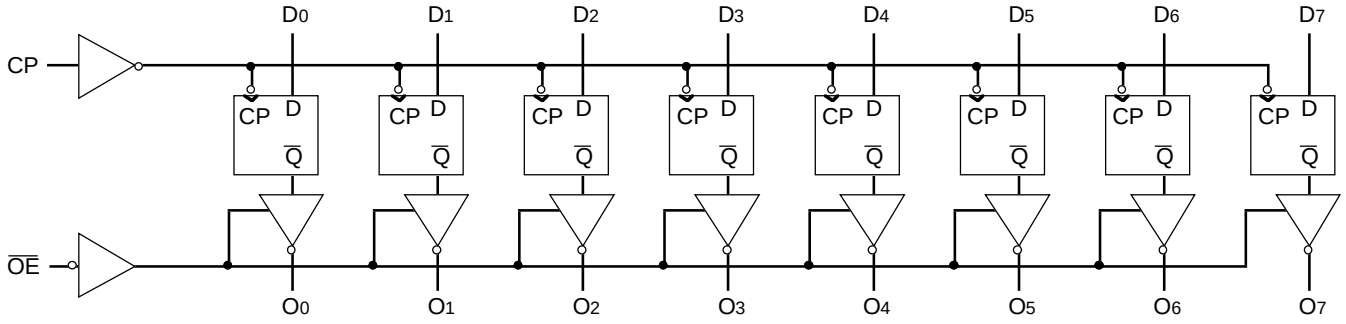
DESCRIPTION:

The IDT54/74FCT374/A/C, IDT54/74FCT534/A/C and IDT54/74FCT574/A/C are 8-bit registers built using an advanced dual metal CMOS technology. These registers consist of eight D-type flip-flops with a buffered common clock and buffered 3-state output control. When the output enable ($\overline{OE}$) is LOW, the eight outputs are enabled. When the $\overline{OE}$ input is HIGH, the outputs are in the high-impedance state.

Input data meeting the set-up and hold time requirements of the D inputs is transferred to the O outputs on the LOW-to-HIGH transition of the clock input.

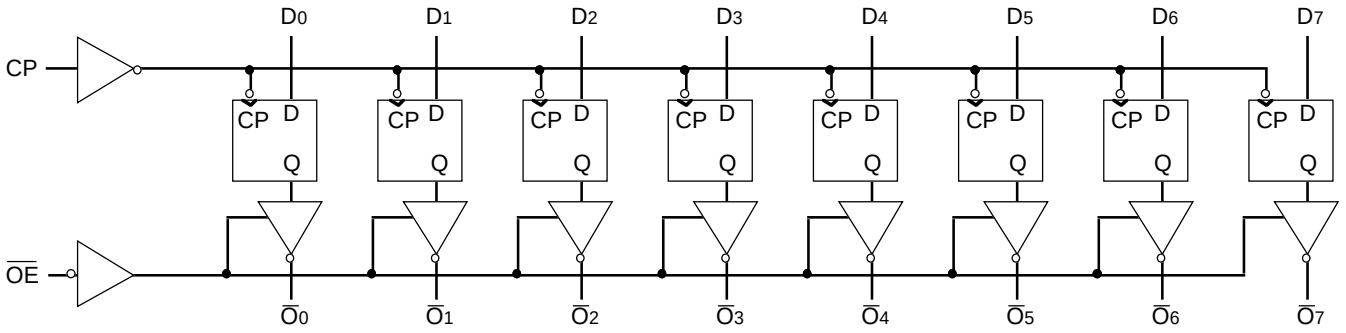
The IDT54/74FCT374/A/C and IDT54/74FCT574/A/C have non-inverting outputs with respect to the data at the D inputs. The IDT54/74FCT534/A/C have inverting outputs.

FUNCTIONAL BLOCK DIAGRAM IDT54/74FCT374 AND IDT54/74FCT574



2603 cnv* 01

FUNCTIONAL BLOCK DIAGRAM IDT54/74FCT534



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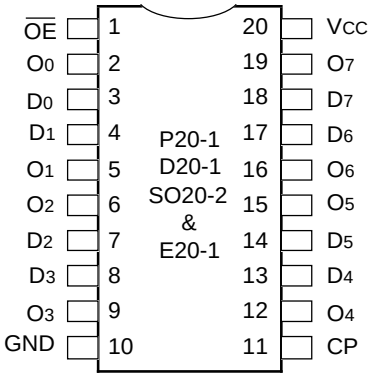
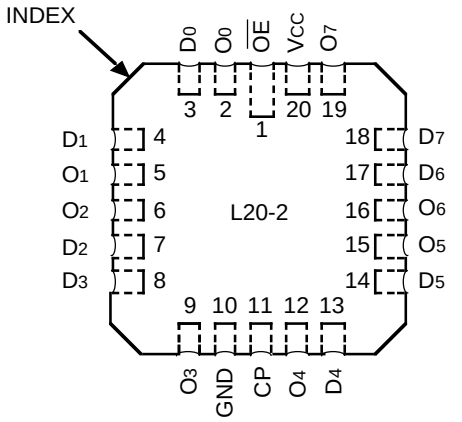
PIN CONFIGURATIONS

IDT54/74FCT374



2603 cnv* 03

DIP/SOIC/CERPACK
TOP VIEW



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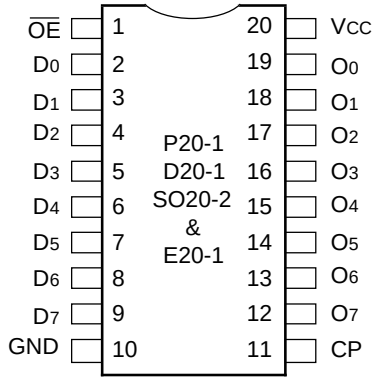
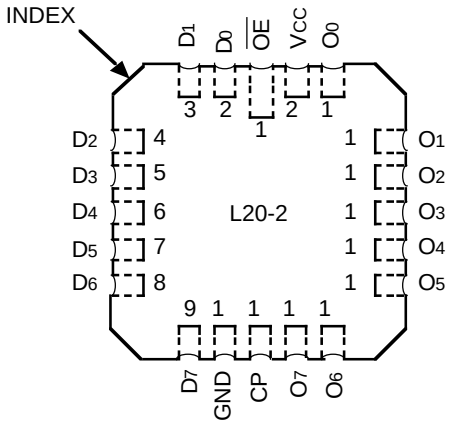
LCC
TOP VIEW

IDT54/74FCT574



2603 cnv* 05

DIP/SOIC/CERPACK
TOP VIEW



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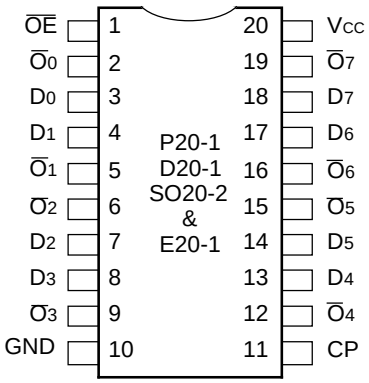
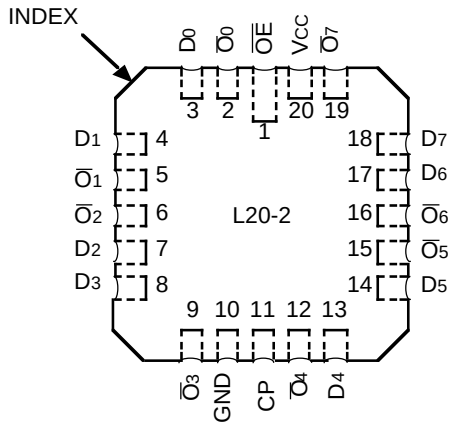
LCC
TOP VIEW

IDT54/74FCT534



2603 cnv* 07

DIP/SOIC/CERPACK
TOP VIEW



2603 cnv* 08

LCC
TOP VIEW

PIN DESCRIPTION

Pin Names	Description
D_N	D flip-flop data inputs.
CP	Clock Pulse for the register. Enters data on LOW-to-HIGH transition.
O_N	3-state outputs, (true).
$\overline{O}_N$	3-state outputs, (inverted).
$\overline{OE}$	Active LOW 3-state Output Enable input.

2603 tbl 06

FUNCTION TABLE[1]

	Inputs			FCT534		FCT374/574	
				Outputs	Internal	Outputs	Internal
Function	$\overline{OE}$	CP	D_N	$\overline{O}_N$	Q_N	O_N	$\overline{Q}_N$
Hi-Z	H	L	X	Z	NC	Z	NC
	H	H	X	Z	NC	Z	NC
Load Register	L	↑	L	H	L	L	H
	L	↑	H	L	H	H	L
	H	↑	L	Z	L	Z	H
	H	↑	H	Z	H	Z	L

NOTE: 2603 tbl 05

1. H = HIGH Voltage Level
   L = LOW Voltage Level
   X = Don't Care
   Z = High Impedance
   NC = No Change
   ↑ = LOW-to-HIGH transition

ABSOLUTE MAXIMUM RATINGS[1]

Symbol	Rating	Commercial	Military	Unit
V_{TERM}[2]	Terminal Voltage with Respect to GND	–0.5 to +7.0	–0.5 to +7.0	V
V_{TERM}[3]	Terminal Voltage with Respect to GND	–0.5 to V_{CC}	–0.5 to V_{CC}	V
T_A	Operating Temperature	0 to +70	–55 to +125	°C
T_{BIAS}	Temperature Under Bias	–55 to +125	–65 to +135	°C
T_{STG}	Storage Temperature	–55 to +125	–65 to +150	°C
P_T	Power Dissipation	0.5	0.5	W
I_{OUT}	DC Output Current	120	120	mA

NOTES: 2603 tbl 01

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability. No terminal voltage may exceed V_{CC} by +0.5V unless otherwise noted.
2. Input and V_{CC} terminals only.
3. Outputs and I/O terminals only.

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter[1]	Conditions	Typ.	Max.	Unit
C_{IN}	Input Capacitance	V_{IN} = 0V	6	10	pF
C_{OUT}	Output Capacitance	V_{OUT} = 0V	8	12	pF

NOTE: 2603 tbl 02

1. This parameter is measured at characterization but not tested.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: V_{LC} = 0.2V; V_{HC} = V_{CC} – 0.2V
Commercial: T_A = 0°C to +70°C, V_{CC} = 5.0V ± 5%; Military: T_A = –55°C to +125°C, V_{CC} = 5.0V ± 10%

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH Level		2.0	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
I_{IH}	Input HIGH Current	V_{CC} = Max.	V_I = V_{CC}	—	—	5	µA
			V_I = 2.7V	—	—	5[4]	
I_{IL}	Input LOW Current		V_I = 0.5V	—	—	–5[4]	
			V_I = GND	—	—	–5	
I_{OZH}	Off State (High Impedance) Output Current	V_{CC} = Max.	V_O = V_{CC}	—	—	10	µA
			V_O = 2.7V	—	—	10[4]	
I_{OZL}			V_O = 0.5V	—	—	–10[4]	
			V_O = GND	—	—	–10	
V_{IK}	Clamp Diode Voltage	V_{CC} = Min., I_N = –18mA		—	–0.7	–1.2	V
I_{OS}	Short Circuit Current	V_{CC} = Max.[3], V_O = GND		–60	–120	—	mA
V_{OH}	Output HIGH Voltage	V_{CC} = 3V, V_{IN} = V_{LC} or V_{HC}, I_{OH} = –32µA		V_{HC}	V_{CC}	—	V
		V_{CC} = Min.	I_{OH} = –300µA	V_{HC}	V_{CC}	—	
		V_{IN} = V_{IH} or V_{IL}	I_{OH} = –12mA MIL.	2.4	4.3	—	
			I_{OH} = –15mA COM'L.	2.4	4.3	—	
V_{OL}	Output LOW Voltage	V_{CC} = 3V, V_{IN} = V_{LC} or V_{HC}, I_{OL} = 300µA		—	GND	V_{LC}	V
		V_{CC} = Min.	I_{OL} = 300µA	—	GND	V_{LC}[4]	
		V_{IN} = V_{IH} or V_{IL}	I_{OL} = 32mA MIL.	—	0.3	0.5	
			I_{OL} = 48mA COM'L.	—	0.3	0.5	

2603 tbl 03

NOTES:
1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient and maximum loading.
3. Not more than one output should be shorted at one time. Duration of the short circuit test should not exceed one second.
4. This parameter is guaranteed but not tested.

POWER SUPPLY CHARACTERISTICS

V_{LC} = 0.2V; V_{HC} = V_{CC} – 0.2V

Symbol	Parameter	Test Conditions[1]		Min.	Typ.[2]	Max.	Unit
I_{CC}	Quiescent Power Supply Current	V_{CC} = Max. $V_{IN} \geq V_{HC}$; $V_{IN} \leq V_{LC}$		—	0.2	1.5	mA
ΔI_{CC}	Quiescent Power Supply Current TTL Inputs HIGH	V_{CC} = Max. V_{IN} = 3.4V[3]		—	0.5	2.0	mA
I_{CCD}	Dynamic Power Supply Current[4]	V_{CC} = Max. Outputs Open $\overline{OE}$ = GND One Input Toggling 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq V_{LC}$	—	0.15	0.25	mA/ MHz
I_C	Total Power Supply Current[6]	V_{CC} = Max. Outputs Open f_{CP} = 10MHz 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq V_{LC}$ (FCT)	—	1.7	4.0	mA
		$\overline{OE}$ = GND fi = 5MHz 50% Duty Cycle One Bit Toggling	V_{IN} = 3.4V V_{IN} = GND	—	2.2	6.0	
		V_{CC} = Max. Outputs Open f_{CP} = 10MHz 50% Duty Cycle	$V_{IN} \geq V_{HC}$ $V_{IN} \leq V_{LC}$ (FCT)	—	4.0	7.8[5]	
		$\overline{OE}$ = GND Eight Bits Toggling fi = 2.5MHz 50% Duty Cycle	V_{IN} = 3.4V V_{IN} = GND	—	6.2	16.8[5]	

NOTES:

2603 tbl 04

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
2. Typical values are at V_{CC} = 5.0V, +25°C ambient.
3. Per TTL driven input (V_{IN} = 3.4V); all other inputs at V_{CC} or GND.
4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.
5. Values for these conditions are examples of the I_{CC} formula. These limits are guaranteed but not tested.
6. $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
   $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$
   I_{CC} = Quiescent Current
   ΔI_{CC} = Power Supply Current for a TTL High Input (V_{IN} = 3.4V)
   D_H = Duty Cycle for TTL Inputs High
   N_T = Number of TTL Inputs at D_H
   I_{CCD} = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
   f_{CP} = Clock Frequency for Register Devices (Zero for Non-Register Devices)
   fi = Input Frequency
   N_i = Number of Inputs at f_i
   All currents are in milliamps and all frequencies are in megahertz.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

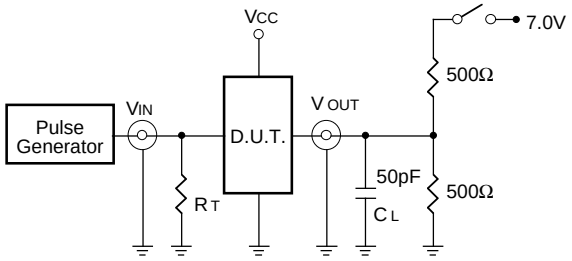
			FCT374/534/574				FCT374A/534A/574A				FCT374C/534C/574C				
			Com'l.		Mil.		Com'l.		Mil.		Com'l.		Mil.		
Symbol	Parameter	Conditions[1]	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Min.[2]	Max.	Unit
t_{PLH} t_{PHL}	Propagation Delay CP to O_N[3]	C_L = 50pF R_L = 500Ω	2.0	10.0	2.0	11.0	2.0	6.5	2.0	7.2	2.0	5.2	2.0	6.2	ns
t_{PZH} t_{PZL}	Output Enable Time		1.5	12.5	1.5	14.0	1.5	6.5	1.5	7.5	1.5	5.5	1.5	6.2	ns
t_{PHZ} t_{PLZ}	Output Disable Time		1.5	8.0	1.5	8.0	1.5	5.5	1.5	6.5	1.5	5.0	1.5	5.7	ns
t_{SU}	Set-up Time HIGH or LOW, D_N to CP		2.0	—	2.0	—	2.0	—	2.0	—	2.0	—	2.0	—	ns
t_H	Hold Time HIGH or LOW, D_N to CP		1.5	—	1.5	—	1.5	—	1.5	—	1.5	—	1.5	—	ns
t_W	CP Pulse Width HIGH or LOW		7.0	—	7.0	—	5.0	—	6.0	—	5.0	—	6.0	—	ns

2603 tbl 07

NOTES:
1. See test circuit and waveforms.
2. Minimum limits are guaranteed but not tested on Propagation Delays.
3. O_N for FCT374 and FCT574, O_N for FCT534.

TEST CIRCUITS AND WAVEFORMS

TEST CIRCUITS FOR ALL OUTPUTS



SWITCH POSITION

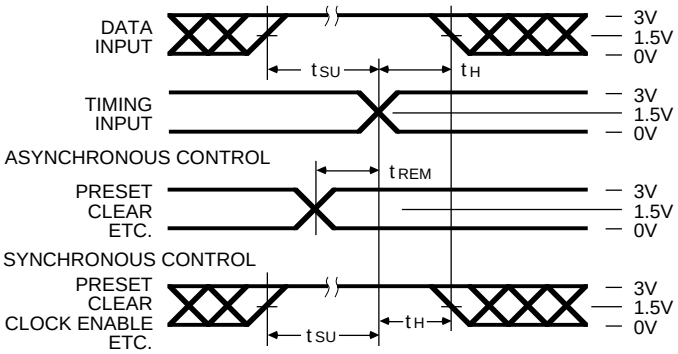
Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

2603 tbl 08

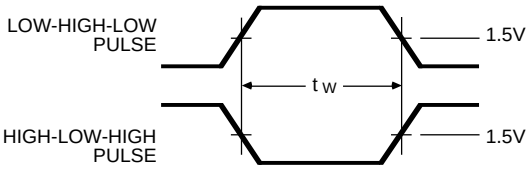
DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

SET-UP, HOLD AND RELEASE TIMES



PULSE WIDTH



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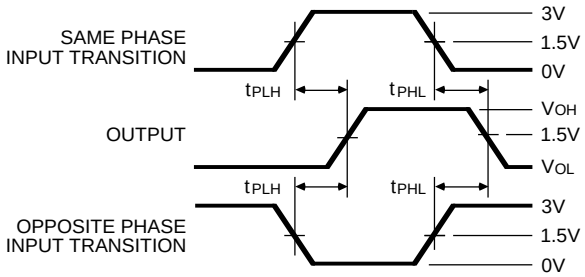
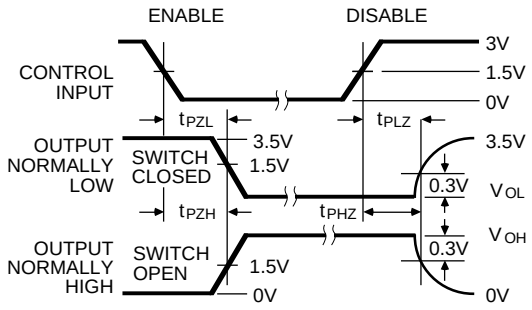


ENABLE AND DISABLE TIMES

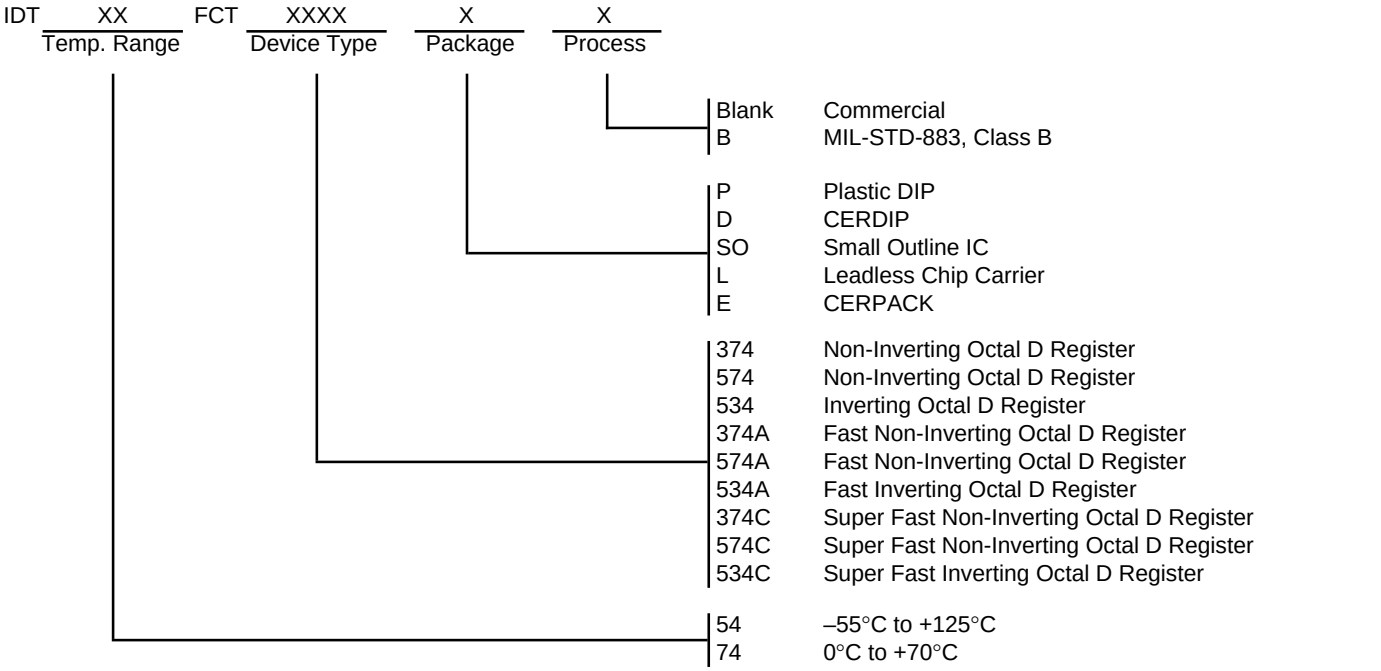


2603 drw 15

NOTES

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
2. Pulse Generator for All Pulses: Rate ≤ 1.0 MHz; $Z_O \leq 50\Omega$; $t_F \leq 2.5$ns; $t_R \leq 2.5$ns.

ORDERING INFORMATION



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